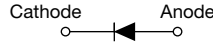




# High Performance Schottky Rectifier, 1 A



DO-214AC (SMA)



### FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



RoHS COMPLIANT HALOGEN FREE

PRODUCT SUMMARY	
Package	DO-214AC (SMA)
$I_{F(AV)}$	1 A
$V_R$	40 V
$V_F$ at $I_F$	0.49 V
$I_{RM}$	26 mA at 125 °C
$T_J$ max.	150 °C
Diode variation	Single die
$E_{AS}$	3.0 mJ

### DESCRIPTION

The VS-10MQ040HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	1	A
$V_{RRM}$		40	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	120	A
$V_F$	1.5 $A_{pk}$ , $T_J = 125 \text{ }^\circ\text{C}$	0.56	V
$T_J$	Range	-55 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10MQ040HM3	UNITS
Maximum DC reverse voltage	$V_R$	40	V
Maximum working peak reverse voltage	$V_{RWM}$		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 4	$I_{F(AV)}$	50 % duty cycle at $T_L = 123 \text{ }^\circ\text{C}$ , rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)	1.5	A
		50 % duty cycle at $T_L = 132 \text{ }^\circ\text{C}$ , rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)	1	
Maximum peak one cycle non-repetitive surge current See fig. 6	$I_{FSM}$	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	120
		10 ms sine or 6 ms rect. pulse		30
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25 \text{ }^\circ\text{C}$ , $I_{AS} = 1 \text{ A}$ , $L = 6 \text{ mH}$	3.0	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical	1.0	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	1 A	$T_J = 25\text{ }^\circ\text{C}$	0.54	V
		1.5 A		0.62	
		1 A	$T_J = 125\text{ }^\circ\text{C}$	0.49	
		1.5 A		0.56	
Maximum reverse leakage current See fig. 2	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	0.5	mA
		$T_J = 125\text{ }^\circ\text{C}$		26	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.36	V
Forward slope resistance	$r_t$			104	$m\Omega$
Typical junction capacitance	$C_T$	$V_R = 10\text{ }V_{DC}$ , $T_J = 25\text{ }^\circ\text{C}$ , test signal = 1 MHz		38	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	$dV/dt$	Rated $V_R$		10 000	V/ $\mu\text{s}$

**Note**(1) Pulse width = 300  $\mu\text{s}$ , duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}$ , $T_{Stg}$			-55 to +150	$^\circ\text{C}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$	DC operation		80	$^\circ\text{C/W}$
Approximate weight				0.07	g
				0.002	oz.
Marking device		Case style SMA (similar D-64)		1F	

**Note**(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

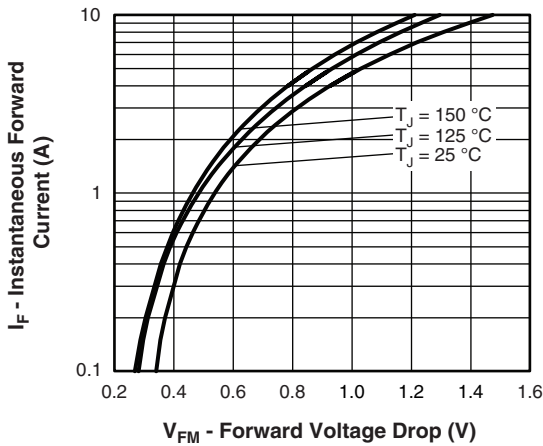


Fig. 1 - Maximum Forward Voltage Drop Characteristics

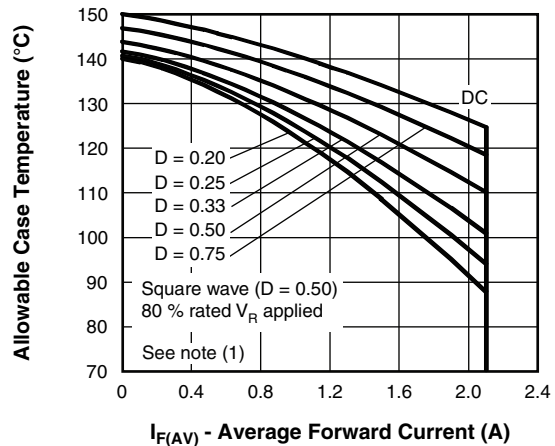


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

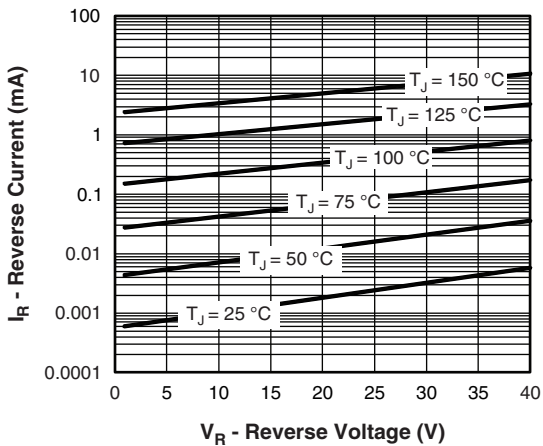


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

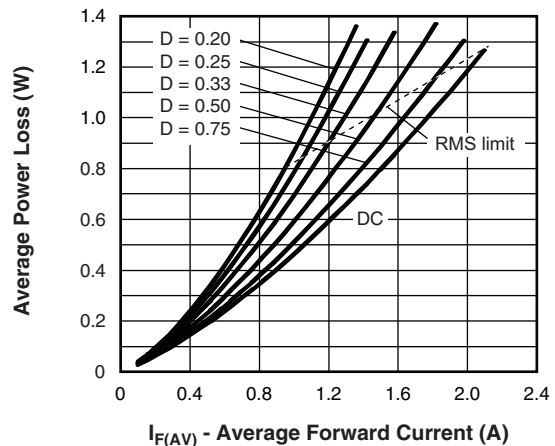


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

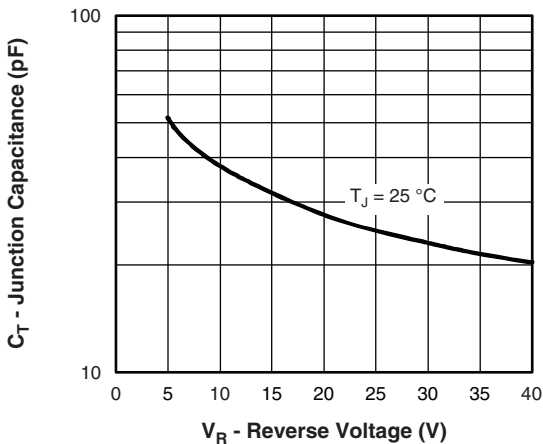


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

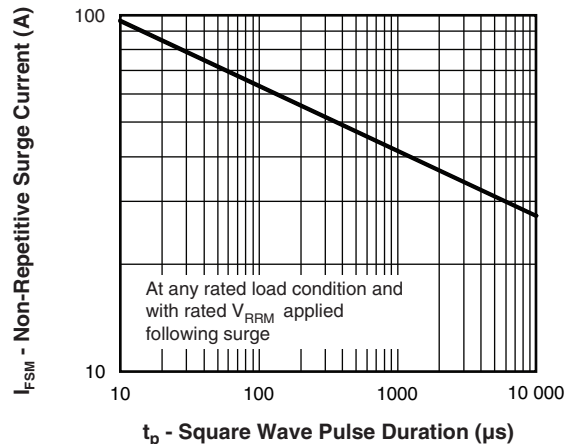


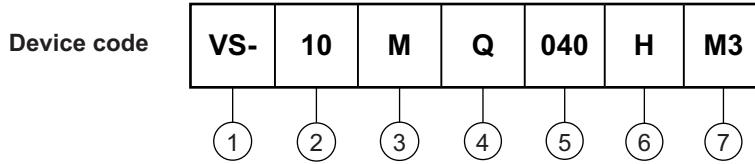
Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

**Note**

(1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



## ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating
- 3** - M = SMA
- 4** - Q = Schottky "Q" series
- 5** - Voltage rating (040 = 40 V)
- 6** - H = AEC-Q101 qualified
- 7** - Environmental digit:  
M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-10MQ040HM3/5AT	5AT	7500	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95400">www.vishay.com/doc?95400</a>
Part marking information	<a href="http://www.vishay.com/doc?95403">www.vishay.com/doc?95403</a>
Packaging information	<a href="http://www.vishay.com/doc?95404">www.vishay.com/doc?95404</a>
SPICE model	<a href="http://www.vishay.com/doc?96007">www.vishay.com/doc?96007</a>

## SMA

**DIMENSIONS** in inches (millimeters)





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